

Data sheet acquired from Harris Semiconductor SCHS050C - Revised October 2003

CMOS 4-Bit Magnitude Comparator

High Voltage Types (20-Volt Rating)

■ CD4063B is a 4-bit magnitude comparator designed for use in computer and logic applications that require the comparison of two 4-bit words. This logic circuit determines whether one 4-bit word (Binary or BCD) is "less than", "equal to", or "greater than" a second 4-bit word.

The CD4063B has eight comparing inputs (A3, B3, through A0, B0), three outputs (A < B, A = B, A > B) and three cascading inputs (A < B, A = B, A > B) that permit systems designers to expand the comparator function to 8, 12, 16 . . . 4N bits. When a single CD4063B is used, the cascading inputs are connected as follows: (A < B) = Iow, (A = B)= high, (A > B) = low.

For words longer than 4 bits, CD4063B devices may be cascaded by connecting the outputs of the less-significant comparator to the corresponding cascading inputs of the more-significant comparator. Cascading inputs (A < B, A = B, and A > B) on the least significant comparator are connected to a low, a high, and a low level, respectively.

The CD4063B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes). This device is pin-compatible with the standard 7485 TTL type.

Features:

- Expansion to 8, 12, 16....4N bits by cascading units
- Medium-speed operation:

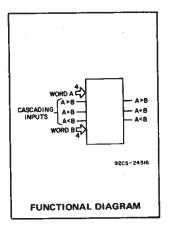
compares two 4-bit words in 250 ns (typ.) at 10 V

- 100% tested for quiescent current at 20 V
- Standardized symmetrical output characteristics
- 5-V, 10-V, and 15-V parametric ratings
- Maximum input current of 1 µA at 18 V over full package temperature range; 100 nA at 18 V and 25°C
- # Noise margin (full package temperature range)

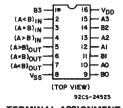
■ Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications:

■ Servo motor controls ■ Process controllers



CD4063B Types



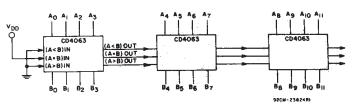
TERMINAL ASSIGNMENT

MAXIMUM RATINGS, Absolute-Maximum Values:

	DC SUPPLY-VOLTAGE RANGE, (VD
0.5V to +20V	Voltages referenced to VSS Termina
0.5V to V _{DD} +0.5V	INPUT VOLTAGE RANGE, ALL INPUT
±10mA	DC INPUT CURRENT, ANY ONE INPU
	POWER DISSIPATION PER PACKAC
500mW	For $T_{\Delta} = -55^{\circ}C$ to $+100^{\circ}C$
Derate Linearity at 12mW/ ^o C to 200mW	For TA = +100°C to +125°C
	DEVICE DISSIPATION PER OUTPUT
ATURE RANGE (All Package Types)	FOR TA = FULL PACKAGE-TEMPI
T _A)55°C to +125°C	OPERATING-TEMPERATURE RANG
g)65°C to +150°C	STORAGE TEMPERATURE RANGE (
ERING);	LEAD TEMPERATURE (DURING SO
.79mm) from case for 10s max ,	At distance 1/16 ± 1/32 inch (1.59

RECOMMENDED OPERATING CONDITIONS For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

operation is arrest and					
	LIĀ	LIMITS			
CHARACTERISTIC	Min.	Max.	UNITS		
Supply-Voltage Range (For T _A =Full Package- Temperature Range)	3	18	٧		



TOTAL TO (COMPARE) + 3 x to (CASCADE), AT VDD = 10V (3 STAGES) = 250 + (2 x 200) = 650 ns (TYP.)

Fig. 1 — Typical speed characteristics of a 12-bit comparator.

CD4063B Types

STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	CONE	AOITIC	IS	LIMI	TS AT I	NDICAT	ED TEN	APERA	TURES (°C)	UNITS		
ISTIC	V _O	VIN	VDD						+25		UNIIS		
	(V)	(V)	(V)	55	-40	+85	+125	Min.	Тур.	Max.			
Quiescent Device	· · -	0,5	5	5	5	150	150		0.04	5			
Current,		0,10	10	10	10	300	300	-	0.04	10	م ا		
IDD Max.		0,15	15	20	20	600	600	-	0.04	20	μА		
	. –	0,20	20	100	100	3000	3000	-	0.08	100	1		
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-			
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6		1		
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	_	7		
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	mA		
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	_	1 .		
Current, IOH Min.	9,5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	_	1		
IOH WIII.	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	-			
Output Voltage:	_	0,5	5		0	.05		_	0	0.05			
Low-Level, VOL Max.	. –	0,10	10		0	.05			0	0.05			
AOL Max.	_	0,15	15		0	.05			0	0.05	V		
Output Voltage:	-	0,5	5	_	4	.95		4.95	5	_			
High-Level,		0,10	10		9	.95		9.95	10		1		
VOH Min.	_	0,15	15		14	.95		14.95	15	-			
Input Low	0.5, 4.5	_	5		1	.5		_	_	1.5			
Voltage,	1, 9	_	10			3		_	_	. ∍3			
VIL Max.	1.5,13.5	_	15			4		_	_	4			
Input High	0.5, 4.5	_	5		3	.5		3.5		_	٧		
Voltage,	1, 9		10			7		7	_	_			
VIH Min.	1.5,13.5	-	15		1	1	11	_	_				
Input Current IJN Max.	-	0,18	18	±0.1	±0.1	±1	±1	_	±10-5	±0.1	μА		

TRUTH TABLE

		#1	NPUTS					OUTDUTE			
	COMPA	RING		(CASCADI	VG	OUTPUTS				
A3, B3	A2, B2	A1, B1	A0, B0	A < B	A = B	A > B	A < B	A = B	A > 8		
A3 > B3	X	Х	Х	Х	×	Х	0	0	1		
A3 = B3	A2 > B2	X	Х -	×	×	х	0	0	1		
A3 = B3	A2 = B2	A1>B1	X ·	×	×	х	0	0	1		
A3 = B3	A2 = B2	A1 = B1	A0 > B0	×	X.	×	0	0	1		
A3 = B3	A2 = B2	A1 = B1	A0 = B0	0	0	1	0	0	1		
A3 = B3	A2 = B2	A1 = B1	A0 = B0	0	1	0	0	1	0		
A3 = B3	A2 = B2	A1 = B1	A0 = 80	1.1	0	0	1	0	0		
A3 = B3	A2 = B2	A1 = B1	A0 < B0	×	Х	X	1	0	0		
A3 = B3	A2 = B2	A1 < B1	×	х	х	X .	1	0	0		
A3 = B3	A2 < B2	x :	X	×	×	X ·	1	0	0		
A3 < B3	x	х	х	·x	i x	x -	- 1	0	0		

X = Don't Care

Logic 1 ≡ High Level

Logic 0 ≡ Low Level

CD4063B Types

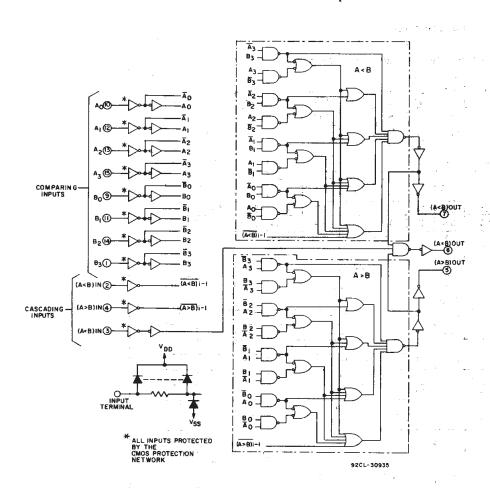


Fig. 2 - Logic diagram for CD4063B.

DYNAMIC ELECTRICAL CHARACTERISTICS

At $T_A = 25^{\circ}C$; Input t_r , $t_f = 20$ ns, $C_L = 50$ pF, $R_L = 200$ k Ω

	TEST CONDI	TIONS	Lii		
CHARACTERISTIC	**************************************	V _{DD} Volts	Тур.	Max.	UNITS
Propagation Delay Time:	!	5	625	1250	1
Comparing Inputs to		10	250	500	
Outputs, tpHL, tpLH		15	175	350	ns
		5	500	1000	1 '''
Cascading Inputs to	. ,	10	200	400	
Outputs, tpHL, tpLH		15	140	280	10 T
		5	100	200	
Transition Time,		10	50	100	ns
tthL/ttlh		15	40	80	
Input Capacitance, CIN	Any Input		5	7,5	pF

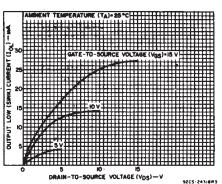


Fig. 3 — Typical output low (sink) current characteristics.

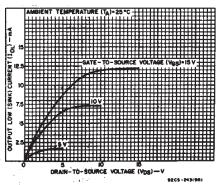


Fig. 4 — Minimum output low (sink) current characteristics.

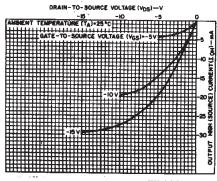


Fig. 5 — Typical output high (source) current characteristics.

Fig. 6 — Minimum output high (source) current characteristics.

CD4063B Types

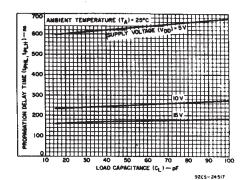


Fig. 7 — Typical propagation delay time vs. load capacitance ("comparing inputs" to outputs).

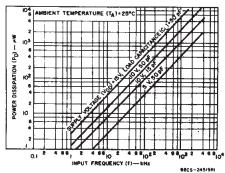


Fig. 10 — Typical power dissipation vs. frequency (see Fig. 12 — dynamic power dissipation test circuit).

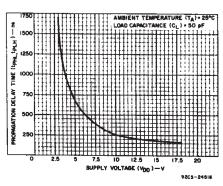


Fig. 8 — Typical propagation delay time vs. supply voltage ("comparing inputs" to outputs).

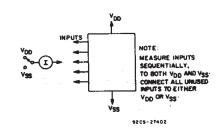


Fig. 11 - Input current test circuit.

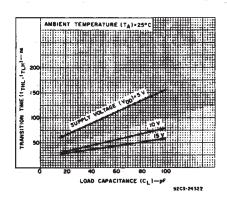


Fig. 9 - Typical transition time vs. load capacitance.

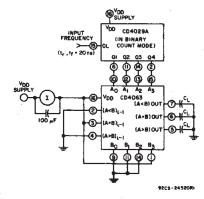


Fig. 12 - Dynamic power dissipation test circuit.

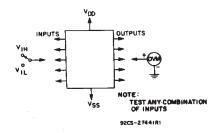


Fig. 13 - Input-voltage test circuit.

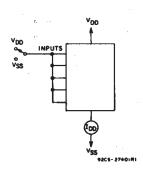
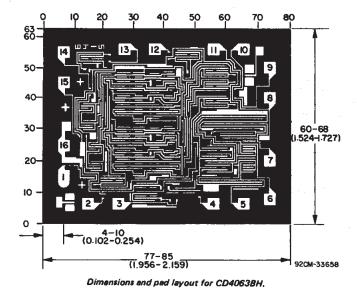


Fig. 14 - Quiescent-device-current test circuit.



Dimensions in parentheses are in millimeters and are derived from the besic inch dimensions as indicated. Grid graduations are in mils $(10^{-3} \, {\rm inch})$.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD4063BE	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4063BE	Samples
CD4063BF	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4063BF	Samples
CD4063BF3A	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4063BF3A	Samples
CD4063BM96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4063BM	Samples
CD4063BM96E4	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4063BM	Samples
CD4063BNSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4063B	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

PACKAGE OPTION ADDENDUM

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OTHER QUALIFIED VERSIONS OF CD4063B, CD4063B-MIL:

Military: CD4063B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4063BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4063BNSR	so	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4063BM96	SOIC	D	16	2500	340.5	336.1	32.0
CD4063BNSR	so	NS	16	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD4063BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4063BE	N	PDIP	16	25	506	13.97	11230	4.32

D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOP



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOF



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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